EE 321 Lab 9 Fall 2002

EE321 - Lab 9

Bipolar Junction Transistors, Part III A Two-Stage BJT Amplifier

Design a two-stage BJT amplifier. Both stages should be common emitter amplifiers, such as Figure 1 of Lab 8. The amplifier should amplify the output of a signal with a 10 k Ω source resistance and a 20 mV amplitude. The output should drive a 2 k Ω load and an amplitude of about 4 V. The amplifier should not respond to DC signals — i.e., capacitively couple the input and output from the amplifier. You can use 2N3904 (NPN) and/or 2N3906 (PNP) BJTs. You can use the circuit from the design problem in Homework 10.

Design and analyze the amplifier before coming to lab. Be sure to determine the bias voltages $(V_E, V_C \text{ and } V_B \text{ for each transistor})$, the overall gain, and the input (R_{in}) and output (R_{out}) resistances.

Build and test your amplifier.

- 1. Measure the bias voltages and compare them to the calculated values.
- 2. Measure the gain at 1 kHz and 10 kHz.
- 3. Measure R_{in} and R_{out} as you did in Lab 8.

When done write a (word-processed) report on the lab (in addition to the notes kept in your lab notebook). The report should be fairly short — include a schematic of the design, the analysis of the bias voltages, gains and input and output resistances, and the measured bias voltages, gains and input and output resistances.